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Pin Configurations

Figure 1. 28-pin TSOP pinout (Top View)

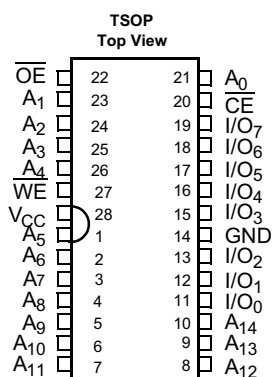
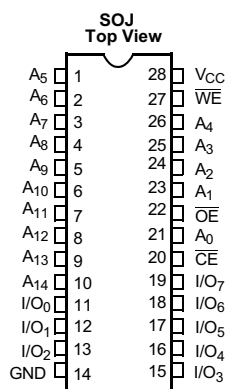


Figure 2. 28-pin SOJ pinout (Top View)



Selection Guide

Description	Condition	-12	-15
Maximum access time (ns)		12	15
Maximum operating current (mA)		55	50
Maximum CMOS standby current (μ A)	Commercial	500	–
	Commercial (L)	50	–
	Industrial	500	500
	Automotive-A	–	500

Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. User guidelines are not tested.

Storage temperature -65 °C to +150 °C

Ambient temperature with power applied -55 °C to +125 °C

Supply voltage on V_{CC} to relative GND ^[1] -0.5 V to +4.6 V

DC voltage applied to outputs in high Z State ^[1] -0.5 V to $V_{CC} + 0.5$ V

DC input voltage ^[1] -0.5 V to $V_{CC} + 0.5$ V

Output current into outputs (LOW) 20 mA

Static discharge voltage (per MIL-STD-883, Method 3015) >2001 V

Latch-up current >200 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0 °C to +70 °C	3.3 V ± 300 mV
Industrial	-40 °C to +85 °C	
Automotive-A	-40 °C to +85 °C	

Electrical Characteristics

Over the Operating Range

Parameter ^[1]	Description	Test Conditions	-12		-15		Unit
			Min	Max	Min	Max	
V_{OH}	Output HIGH voltage	Min V_{CC} , $I_{OH} = -2.0$ mA	2.4	–	2.4	–	V
V_{OL}	Output LOW voltage	Min V_{CC} , $I_{OL} = 4.0$ mA	–	0.4	–	0.4	V
V_{IH}	Input HIGH voltage		2.2	$V_{CC} + 0.3$	2.2	$V_{CC} + 0.3$	V
V_{IL} ^[1]	Input LOW voltage		-0.3	0.8	-0.3	0.8	V
I_{IX}	Input leakage current		-1	+1	-1	+1	μA
I_{OZ}	Output leakage current	$GND \leq V_{IN} \leq V_{CC}$, Output disabled	-5	+5	-5	+5	μA
I_{CC}	V_{CC} operating supply current	Max V_{CC} , $I_{OUT} = 0$ mA, $f = f_{MAX} = 1/t_{RC}$	–	55	–	50	mA
I_{SB1}	Automatic CE power-down current – TTL inputs	Max V_{CC} , $\overline{CE} \geq V_{IH}$, $V_{IN} \geq V_{IH}$, or $V_{IN} \leq V_{IL}$, $f = f_{MAX}$	Commercial	–	5	–	mA
			Commercial (L)	–	4	–	mA
			Industrial	–	5	–	mA
			Automotive-A	–	–	5	mA
I_{SB2}	Automatic CE Power-down current – CMOS inputs ^[2]	Max V_{CC} , $\overline{CE} \geq V_{CC} - 0.3$ V, $V_{IN} \geq V_{CC} - 0.3$ V, or $V_{IN} \leq 0.3$ V, $WE \geq V_{CC} - 0.3$ V or $WE \leq 0.3$ V, $f = f_{MAX}$	Commercial	–	500	–	μA
			Commercial (L)	–	50	–	μA
			Industrial	–	500	–	μA
			Automotive-A	–	–	500	μA

Notes

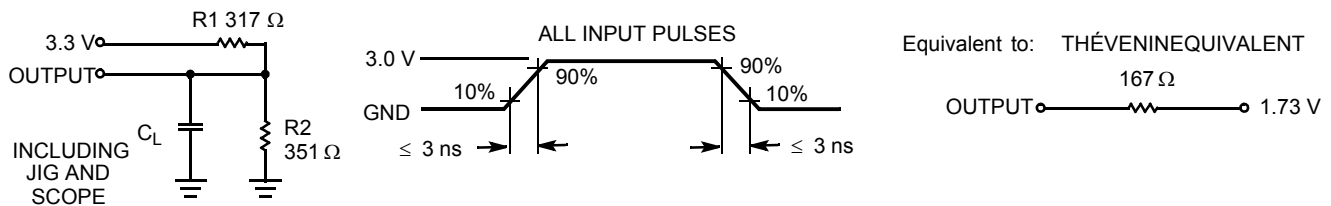
1. Minimum voltage is equal to -2.0 V for pulse durations of less than 20 ns.
2. Device draws low standby current regardless of switching on the addresses.

Capacitance

Parameter ^[3]	Description	Test Conditions	Max	Unit
C_{IN} : Addresses	Input capacitance	$T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$, $V_{CC} = 3.3\text{ V}$	5	pF
C_{IN} : Controls			6	pF
C_{OUT}	Output capacitance		6	pF

AC Test Loads and Waveforms

Figure 3. AC Test Loads and Waveforms ^[4]



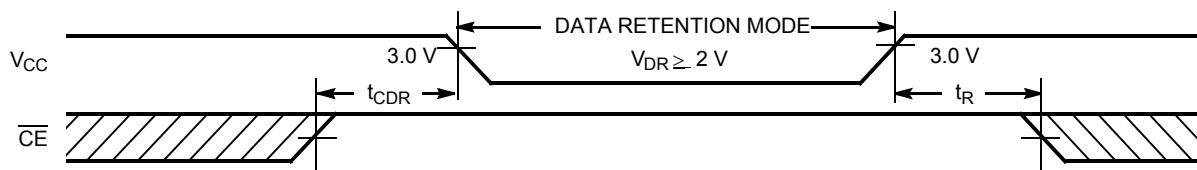
Data Retention Characteristics

(Over the Operating Range - L version only)

Parameter	Description	Conditions	Min	Max	Unit
V_{DR}	V_{CC} for data retention		2.0	—	V
I_{CCDR}	Data retention current	$V_{CC} = V_{DR} = 2.0\text{ V}$, $\overline{CE} \geq V_{CC} - 0.3\text{ V}$, $V_{IN} \geq V_{CC} - 0.3\text{ V}$ or $V_{IN} \leq 0.3\text{ V}$	0	20	μA
t_{CDR}	Chip deselect to data retention time		0	—	ns
t_R	Operation recovery time		t_{RC}	—	ns

Data Retention Waveform

Figure 4. Data Retention Waveform



Notes

- Tested initially and after any design or process changes that may affect these parameters.
- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified I_{OL}/I_{OH} and capacitance $C_L = 30\text{ pF}$.

Switching Characteristics

Over the Operating Range

Parameter ^[5]	Description	-12		-15		Unit
		Min	Max	Min	Max	
Read Cycle						
t _{RC}	Read cycle time	12	–	15	–	ns
t _{AA}	Address to data valid	–	12	–	15	ns
t _{OHA}	Data hold from address change	3	–	3	–	ns
t _{ACE}	$\overline{CE}$ LOW to data valid	–	12	–	15	ns
t _{DOE}	$\overline{OE}$ LOW to data valid	–	5	–	6	ns
t _{LZOE}	$\overline{OE}$ LOW to low Z ^[6]	0	–	0	–	ns
t _{HZOE}	$\overline{OE}$ HIGH to high Z ^[6, 7]	–	5	–	6	ns
t _{LZCE}	$\overline{CE}$ LOW to low Z ^[6]	3	–	3	–	ns
t _{HZCE}	$\overline{CE}$ HIGH to high Z ^[6, 7]	–	6	–	7	ns
t _{PU}	$\overline{CE}$ LOW to power-up	0	–	0	–	ns
t _{PD}	$\overline{CE}$ HIGH to power-down	–	12	–	15	ns
Write Cycle ^[8, 9]						
t _{WC}	Write cycle time	12	–	15	–	ns
t _{SCE}	$\overline{CE}$ LOW to write end	8	–	10	–	ns
t _{AW}	Address setup to write end	8	–	10	–	ns
t _{HA}	Address hold from write end	0	–	0	–	ns
t _{SA}	Address setup to write start	0	–	0	–	ns
t _{PWE}	$\overline{WE}$ pulse width	8	–	10	–	ns
t _{SD}	Data setup to write end	7	–	8	–	ns
t _{HD}	Data hold from write end	0	–	0	–	ns
t _{HZWE}	$\overline{WE}$ low to high Z ^[8]	–	7	–	7	ns
t _{LZWE}	$\overline{WE}$ high to low Z ^[6]	3	–	3	–	ns

Notes

- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V, and output loading of the specified I_{OL}/I_{OH} and capacitance $C_L = 30$ pF.
- At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any given device.
- t_{HZOE} , t_{HZCE} , t_{HZWE} are specified with $C_L = 5$ pF as in AC Test Loads. Transition is measured ± 500 mV from steady state voltage.
- The internal write time of the memory is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.
- The minimum write cycle time for write cycle #3 ($\overline{WE}$ controlled, $\overline{OE}$ LOW) is the sum of t_{HZWE} and t_{SD} .

Switching Waveforms

Figure 5. Read Cycle No. 1 ^[10, 11]

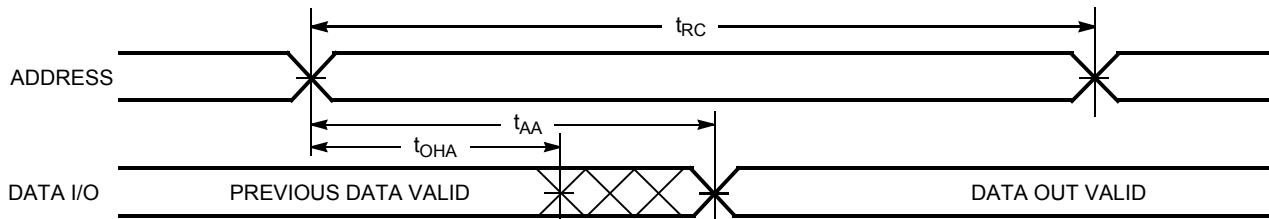
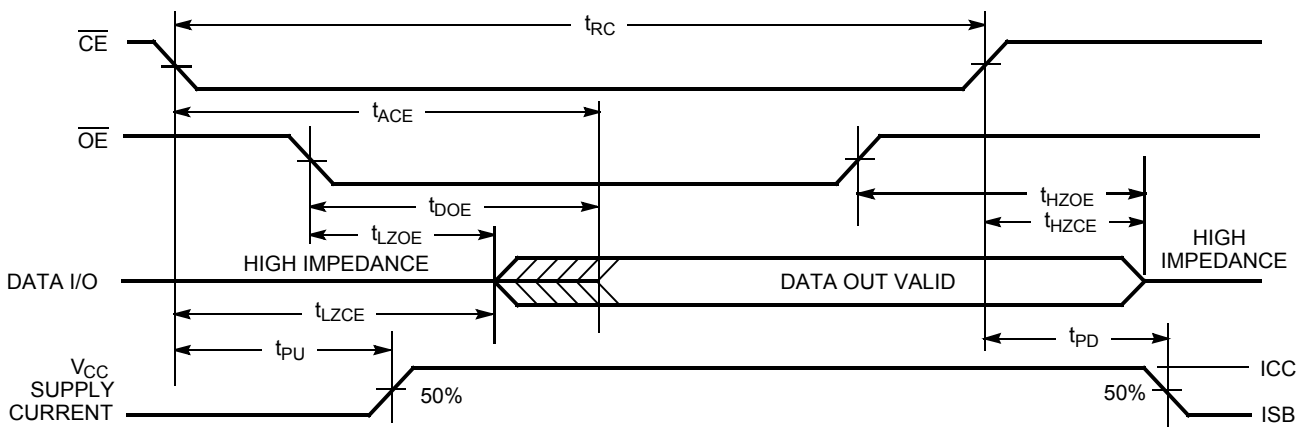


Figure 6. Read Cycle No. 2 ^[11, 12]



Notes

10. Device is continuously selected. $\overline{OE}$, $\overline{CE} = V_{IL}$.
11. $\overline{WE}$ is HIGH for read cycle.
12. Address valid prior to or coincident with $\overline{CE}$ transition LOW.

Switching Waveforms (continued)

Figure 7. Write Cycle No. 1 ($\overline{\text{WE}}$ Controlled) [13, 14, 15]

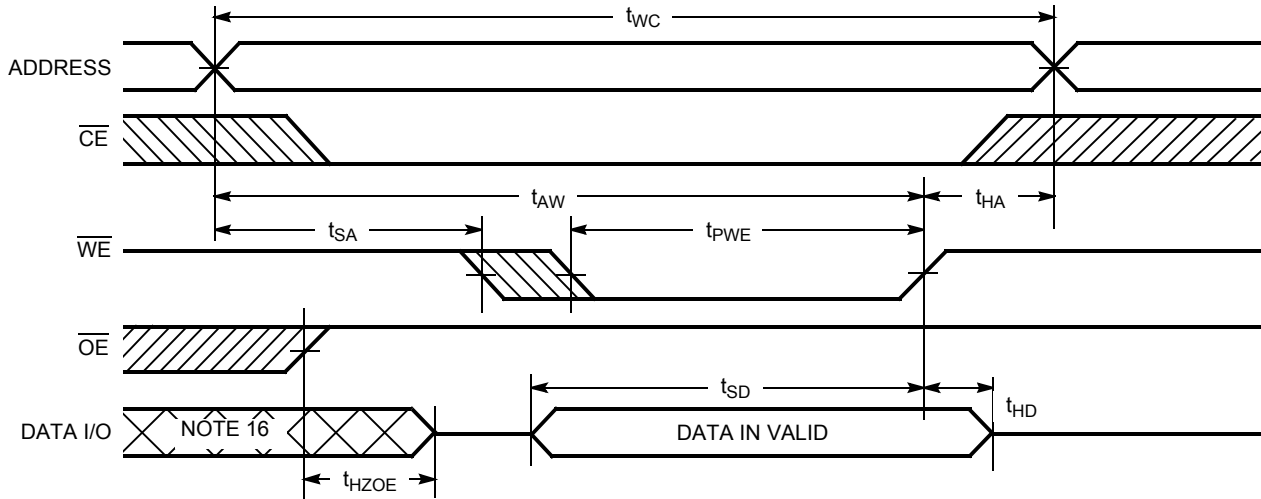
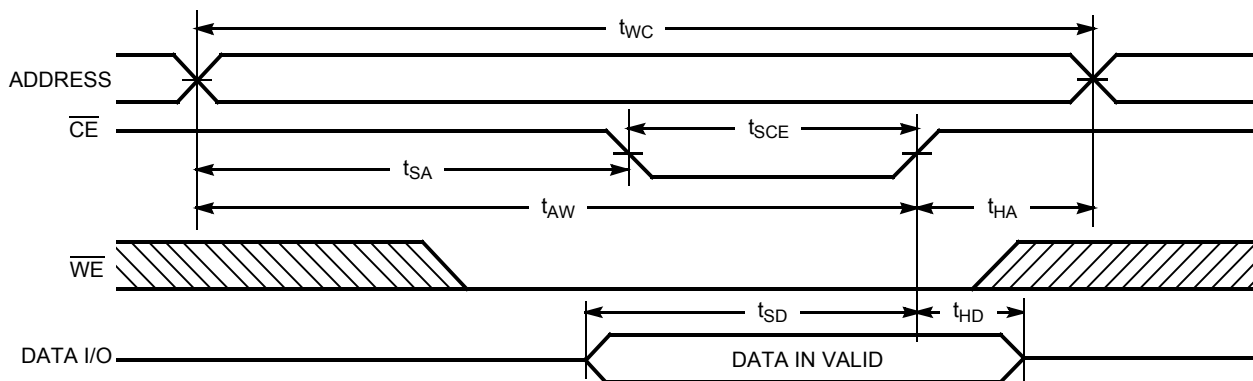


Figure 8. Write Cycle No. 2 ($\overline{\text{CE}}$ Controlled) [13, 14, 15]



Notes

13. The internal write time of the memory is defined by the overlap of $\overline{\text{CE}}$ LOW and $\overline{\text{WE}}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.

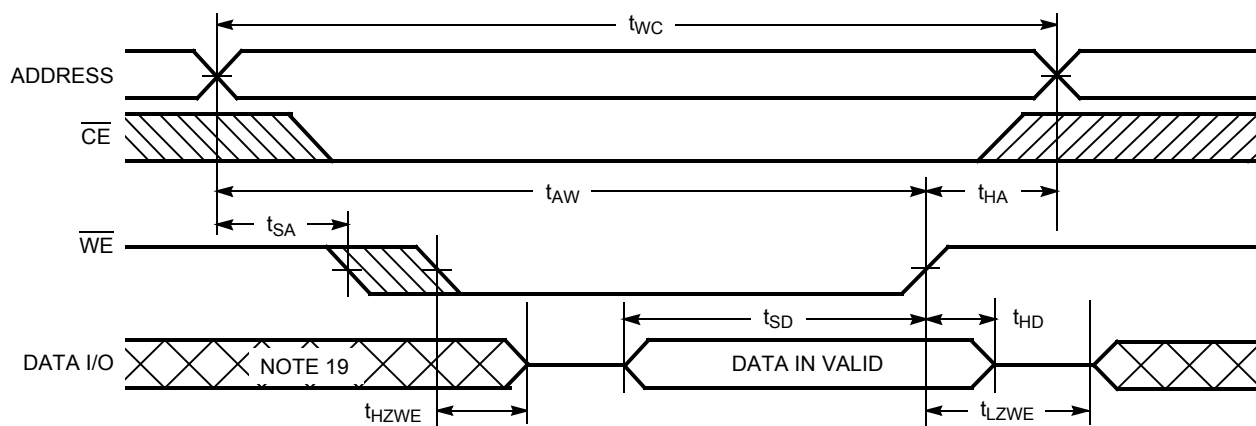
14. Data I/O is high impedance if $\text{OE} = V_{\text{IH}}$.

15. If $\overline{\text{CE}}$ goes HIGH simultaneously with $\overline{\text{WE}}$ HIGH, the output remains in a high-impedance state.

16. During this period, the I/Os are in the output state and input signals should not be applied.

Switching Waveforms (continued)

Figure 9. Write Cycle No. 3 ($\overline{WE}$ Controlled, $\overline{OE}$ LOW) [17, 18]



Notes

17. The minimum write cycle time for write cycle #3 ($\overline{WE}$ controlled, $\overline{OE}$ LOW) is the sum of t_{HZWE} and t_{SD} .
18. If $\overline{CE}$ goes HIGH simultaneously with $\overline{WE}$ HIGH, the output remains in a high-impedance state.
19. During this period, the I/Os are in the output state and input signals should not be applied.

Truth Table

$\overline{\text{CE}}$	$\overline{\text{WE}}$	$\overline{\text{OE}}$	Input/Output	Mode	Power
H	X	X	High Z	Deselect/Power-down	Standby (I_{SB})
L	H	L	Data Out	Read	Active (I_{CC})
L	L	X	Data In	Write	Active (I_{CC})
L	H	H	High Z	Deselect, Output disabled	Active (I_{CC})

Ordering Information

Cypress offers other versions of this type of product in many different configurations and features. The following table contains only the list of parts that are currently available.

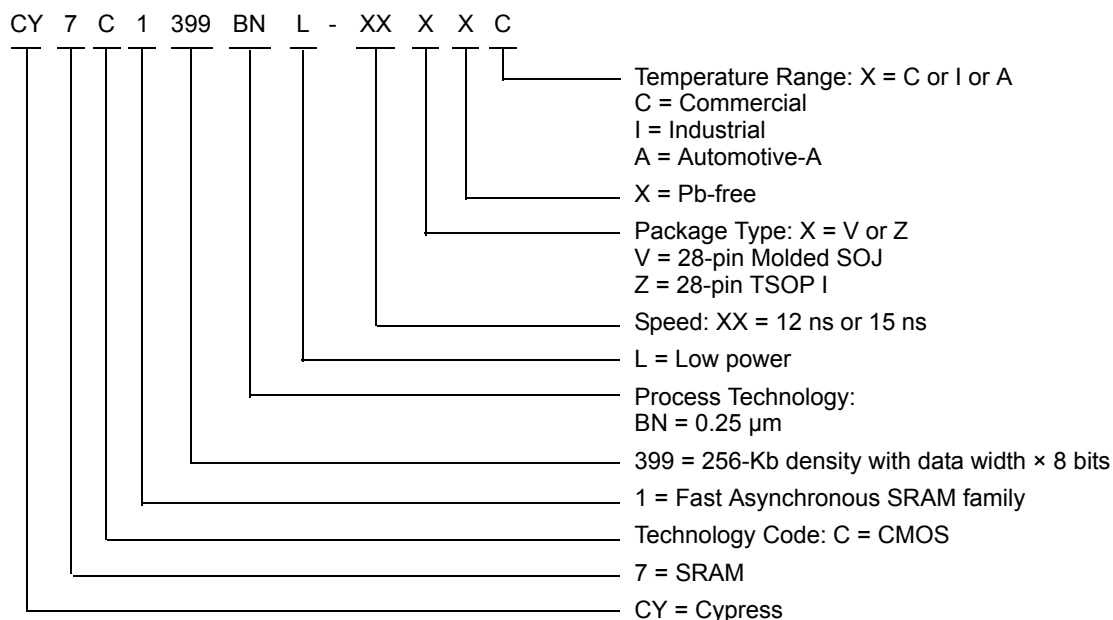
For a complete listing of all options, visit the Cypress website at www.cypress.com and refer to the product summary page at <http://www.cypress.com/products> or contact your local sales representative.

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Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
12	CY7C1399BN-12VXC	51-85031	28-pin molded SOJ (Pb-free)	Commercial
	CY7C1399BN-12ZXC	51-85071	28-pin TSOP I (Pb-free)	
	CY7C1399BNL-12ZXC		28-pin TSOP I (Pb-free)	
	CY7C1399BN-12VXI	51-85031	28-pin molded SOJ (Pb-free)	Industrial
15	CY7C1399BN-15ZXI	51-85071	28-pin TSOP I (Pb-free)	Industrial
	CY7C1399BN-15VXA	51-85031	28-pin molded SOJ (Pb-free)	Automotive-A

Contact your local sales representative regarding availability of these parts.

Ordering Code Definitions

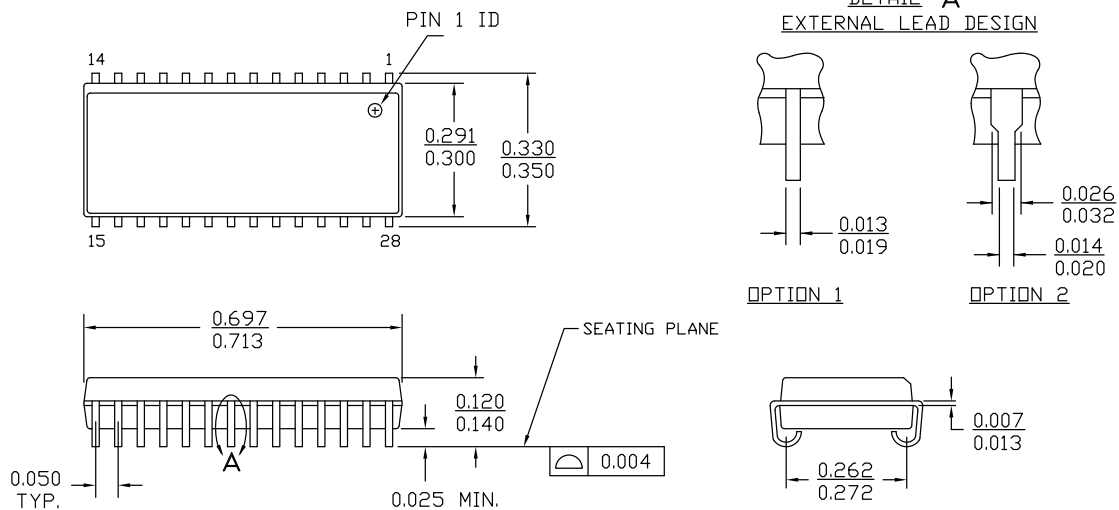


Package Diagrams

Figure 10. 28-pin SOJ (300 Mils) V28.3 (Molded SOJ V21) Package Outline, 51-85031

NOTE :

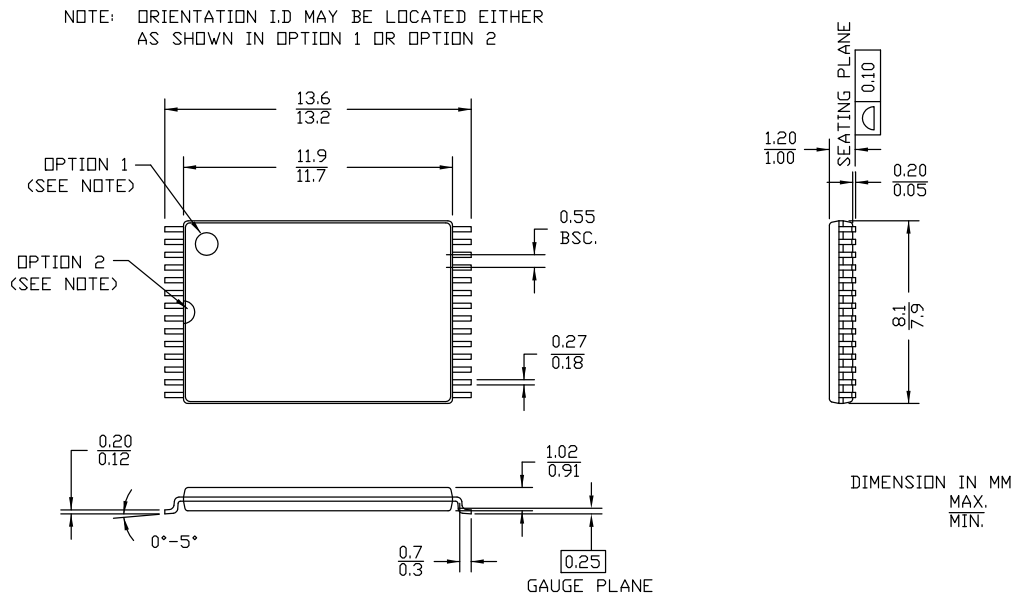
1. JEDEC STD REF MO088
2. BODY LENGTH DIMENSION DOES NOT INCLUDE MOLD PROTRUSION/END FLASH
MOLD PROTRUSION/END FLASH SHALL NOT EXCEED 0.006 in (0.152 mm) PER SIDE
3. DIMENSIONS IN INCHES MIN.
MAX.



51-85031 *E

Package Diagrams (continued)

Figure 11. 28-pin TSOP I (8 × 13.4 × 1.2 mm) Z28 (Standard) Package Outline, 51-85071



51-85071 *I

Acronyms

Acronym	Description
$\overline{\text{CE}}$	Chip Enable
CMOS	Complementary Metal Oxide Semiconductor
I/O	Input/Output
$\overline{\text{OE}}$	Output Enable
SRAM	Static Random Access Memory
TSOP	Thin Small Outline Package
$\overline{\text{WE}}$	Write Enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
$^{\circ}\text{C}$	degree Celsius
MHz	megahertz
μA	microampere
mA	milliampere
mV	millivolt
mW	milliwatt
ns	nanosecond
pF	picofarad
V	volt
W	watt

Document History Page

Document Title: CY7C1399BN, 256-Kbit (32 K × 8) Static RAM Document Number: 001-06490				
Revision	ECN	Orig. of Change	Submission Date	Description of Change
**	423877	NXR	See ECN	New data sheet.
*A	498575	NXR	See ECN	Added Automotive-A range Removed I _{OS} parameter from DC Electrical Characteristics table Updated Ordering Information table.
*B	2896382	AJU	03/19/2010	Removed obsolete part numbers from Ordering Information table and updated package diagrams.
*C	3053362	PRAS	10/08/2010	Removed pruned part numbers CY7C1399BNL-15VXC and CY7C1399BNL-15VXCT. Added Ordering Code Definitions.
*D	3383869	TAVA	09/26/2011	Added Commercial temperature range under Features section on page 1. Removed reference to AN1064-SRAM System Design Guidelines on page 1. Modified the notes in figures under Read cycle and Write cycle sections. Updated template according to current Cypress standards. Rearranged sections for better clarity. Revised package diagrams. Added Acronyms and Units of measure.
*E	4121360	VINI	09/12/2013	Updated in new template. Completing Sunset Review.

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